

# Product Specification PE43704

Product Description

The PE43704 is a HaRP<sup>TM</sup> technology-enhanced, high linearity, 7-bit 50 $\Omega$  RF digital step attenuator (DSA). It offers maximum power handling of 28 dBm up to 8 GHz and covers a 31.75 dB attenuation range in 0.25 dB, 0.5 dB, or 1.0 dB steps. The PE43704 is a pin-compatible version of PE43703. It provides multiple CMOS control interfaces and an optional Vss<sub>EXT</sub> bypass mode to improve spurious performance. It maintains high attenuation accuracy over frequency and temperature and exhibits very low insertion loss and low power consumption. No blocking capacitors are required if DC voltage is not present on the RF ports.

The PE43704 is manufactured on pSemi's UltraCMOS<sup>®</sup> process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

# Figure 1. Package Type

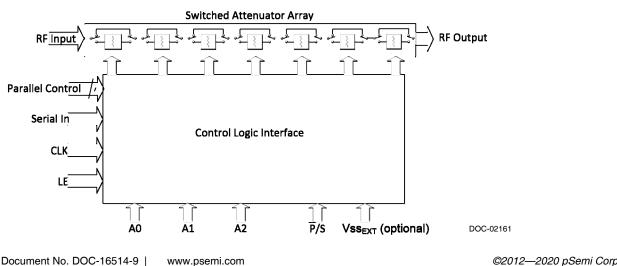


# Figure 2. Functional Diagram

UltraCMOS<sup>®</sup> RF Digital Step Attenuator, 7-bit, 31.75 dB with Optional Vss<sub>EXT</sub> Bypass Mode 9 kHz - 8 GHz

#### Features

- HaRP<sup>™</sup> technology enhanced
- Safe attenuation state transitions
- Attenuation options: covers a 31.75 dB range in 0.25 dB, 0.5 dB, or 1.0 dB steps
  - 0.25 dB monotonicity for  $\leq$  6 GHz
  - 0.50 dB monotonicity for  $\leq$  7 GHz
  - 1.00 dB monotonicity for  $\leq$  8 GHz
- High power handling @ 8 GHz in  $50\Omega$ 
  - 28 dBm CW
  - 31 dBm instantaneous power
- High linearity
  - IIP3 of 61 dBm
- 1.8V/3.3V control logic
- Programming modes
  - Direct parallel
  - Latched parallel
  - Serial
  - Serial Addressable
- High-attenuation state @ power-up (PUP)
- ESD performance
  - 1.5kV HBM on all pins



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# Table 1. Electrical Specifications: 0.25 dB steps @ +25°C, $V_{DD}$ = 2.3V to 5.5V, $Vss_{EXT}$ = 0V or $V_{DD}$ = 3.4V to 5.5V, $Vss_{EXT}$ = -3.4V ( $Z_s$ = $Z_L$ = 50 $\Omega$ ) unless otherwise noted

Parameter	Condition	Frequency	Min	Тур	Мах	Unit
Operating frequency			9 kHz		6000 MHz	As shown
Attenuation range	0.25 dB Step			0 – 31.75		dB
Insertion loss		9 kHz – 2 GHz 2 GHz – 4 GHz 4 GHz – 6 GHz		1.3 1.7 2.4	1.6 2.0 2.8	dB dB dB
	0 dB – 15.75 dB Attenuation settings	9 KHz ≤ 4 GHz			+ (0.15 + 4.5% of Attenuation Setting) - (0.1 + 2% of Attenuation Setting)	dB dB
Attenuation error	o de 15.75 de Alcondation solangs	4 GHz – 6 GHz			+ (0.15 + 6% of Attenuation Setting) - (0.15+1% of Attenuation Setting)	dB dB
		9 KHz ≤ 4 GHz			+ (0.15 + 4.5% of Attenuation Setting) - (0.1 + 2.5% of Attenuation Setting)	dB dB
	16 dB – 31.75 dB Attenuation settings	4 GHz – 6 GHz			+ (0.25 + 6.5% of Attenuation Setting) - (0.2+1% of Attenuation Setting)	dB dB
Return loss	Input port	9 kHz – 4 GHz 4 GHz – 6 GHz		20 15		dB dB
Return loss	Output port	9 kHz – 4 GHz 4 GHz – 6 GHz		17 13		dB dB
Relative phase	0 dB – 31.75 dB Attenuation settings	9 kHz – 6 GHz		58		deg
Input 1dB compression point <sup>1</sup>		50 MHz – 6 GHz	32	34		dBm
IIP3	Two tones at +18 dBm, 20 MHz spacing	50 MHz – 6 GHz		61		dBm
Typical spurious value <sup>2</sup>	Vss <sub>EXT</sub> = 0V			-140		dBm
RF Trise/Tfall	10% / 90% RF			600		ns
Settling time	RF settled to within 0.05 dB of final value			2		μs
Switching time	50% CTRL to 90% or 10% RF			1.1		μs

Notes: 1. The input 1dB compression point is a linearity figure of merit. Refer to Table 5 for the RF input power P<sub>IN</sub> (50Ω)

2. To prevent negative voltage generator spurs, supply -3.4 volts to Vss<sub>EXT</sub>



# Table 2. Electrical Specifications: 0.5 dB steps @ +25°C, $V_{DD}$ = 2.3V to 5.5V, $Vss_{EXT}$ = 0V or $V_{DD}$ = 3.4V to 5.5V, $Vss_{EXT}$ = -3.4V ( $Z_s$ = $Z_L$ = 50 $\Omega$ ) unless otherwise noted

Parameter	Condition	Frequency	Min	Тур	Мах	Unit
Operating frequency			9 kHz		7000 MHz	As shown
Attenuation range	0.5 dB Step			0 – 31.5		dB
Insertion loss		9 kHz – 2 GHz 2 GHz – 4 GHz 4 GHz – 6 GHz 6 GHz – 7 GHz		1.3 1.7 2.4 2.5	1.6 2.0 2.8 2.9	dB dB dB dB
		9 KHz ≤ 4 GHz			+ (0.15 + 4.5% of Attenuation Setting) - (0.1 + 2% of Attenuation Setting)	dB dB
Attenuation error	0 dB – 15.5 dB Attenuation settings	4 GHz – 7 GHz			+ (0.25 + 5.5% of Attenuation Setting) - (0.15+1% of Attenuation Setting)	dB dB
		9 KHz ≤ 4 GHz			+ (0.15 + 4.5% of Attenuation Setting) - (0.1 + 2.5% of Attenuation Setting)	dB dB
	16 dB – 31.5 dB Attenuation settings	4 GHz – 7 GHz			+ (0.25 + 6.5% of Attenuation Setting) - (0.25 + 2.5% of Attenuation Setting)	dB dB
Return loss	Input port	9 kHz – 4 GHz 4 GHz – 7 GHz		20 16		dB dB
Return loss	Output port	9 kHz – 4 GHz 4 GHz – 7 GHz		17 14		dB dB
Relative phase	0 dB – 31.5 dB Attenuation settings	9 kHz – 7 GHz		65		deg
Input 1dB compression point <sup>1</sup>		50 MHz – 7 GHz	32	34		dBm
IIP3	Two tones at +18 dBm, 20 MHz spacing	50 MHz – 7 GHz		61		dBm
Typical spurious value <sup>2</sup>	Vss <sub>EXT</sub> = 0V			-140		dBm
RF Trise/Tfall	10% / 90% RF			600		ns
Settling time	RF settled to within 0.05 dB of final value			2		μs
Switching time	50% CTRL to 90% or 10% RF			1.1		μs

Notes: 1. The input 1dB compression point is a linearity figure of merit. Refer to Table 5 for the RF input power  $P_{IN}$  (50 $\Omega$ )

2. To prevent negative voltage generator spurs, supply –3.4 volts to  $\mathsf{Vss}_{\mathsf{EXT}}$ 

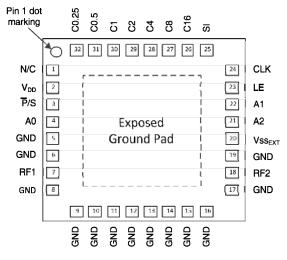


# Table 3. Electrical Specifications: 1 dB steps @ +25°C, $V_{DD}$ = 2.3V to 5.5V, $Vss_{EXT}$ = 0V or $V_{DD}$ = 3.4V to 5.5V, $Vss_{EXT}$ = -3.4V ( $Z_s$ = $Z_L$ = 50 $\Omega$ ) unless otherwise noted

Parameter	Condition	Frequency	Min	Тур	Max	Unit
Operating frequency			9 kHz		8000 MHz	As shown
Attenuation range	1 dB Step			0 - 31		dB
Insertion loss		9 kHz – 2 GHz 2 GHz – 4 GHz 4 GHz – 6 GHz 6 GHz – 8 GHz		1.3 1.7 2.4 2.9	1.6 2.0 2.8 3.2	dB dB dB dB
		9 kHz ≤ 4 GHz			+ (0.15 + 4.5% of Attenuation Setting) - (0.1 + 2% of Attenuation Setting)	dB dB
	0 dB – 15 dB Attenuation settings	4 GHz ≤ 7 GHz			+ (0.25 + 6% of Attenuation Setting) - (0.25 + 2% of Attenuation Setting)	dB dB
		7 GHz – 8 GHz			+ (0.25 + 7% of Attenuation Setting) - (0.25 + 2% of Attenuation Setting)	dB dB
Attenuation error		9 kHz ≤ 4 GHz			+ (0.15 + 4.5% of Attenuation Setting) - (0.1 + 2.5% of Attenuation Setting)	dB dB
	16dB – 31 dB Attenuation settings	4 GHz ≤ 7 GHz			+ (0.25 + 6.5% of Attenuation Setting) - (0.25 + 3% of Attenuation Setting)	dB dB
		7 GHz – 8 GHz			+ (0.25 + 7% of Attenuation Setting) - (0.25 + 4% of Attenuation Setting)	dB dB
Return loss	Input port	9 kHz – 4 GHz 4 GHz – 8 GHz		20 14.5		dB dB
Return loss	Output port	9 kHz – 4 GHz 4 GHz – 8 GHz		17 12.5		dB dB
Relative phase	0 dB – 31 dB Attenuation settings	9 kHz – 8 GHz		80		deg
Input 1dB compression point <sup>1</sup>		50 MHz – 8 GHz	32	34		dBm
IIP3	Two tones at +18 dBm, 20 MHz spacing	50 MHz – 8 GHz		61		dBm
Typical spurious value <sup>2</sup>	Vss <sub>EXT</sub> = 0V			-140		dBm
RF Trise/Tfall	10% / 90% RF			600		ns
Settling time	RF settled to within 0.05 dB of final value			2		μs
Switching time Notes: 1. The input 1dB compres	50% CTRL to 90% for 10% RF.	<i>le 5</i> for the RF input po	wer P <sub>IN</sub> (50Ω	1.1		μs



#### Figure 3. Pin Configuration (Top View)



#### **Table 4. Pin Descriptions**

Pin #	Pin Name	Description
1	N/C	No connect
2	V <sub>DD</sub>	Supply voltage
3	₽/S	Serial/parallel mode select
4	A0	Address bit A0 connection
5, 6, 8-17, 19	GND	Ground
7	RF1 <sup>1</sup>	RF1 port (RF input)
18	RF2 <sup>1</sup>	RF2 port (RF output)
20	Vss <sub>EXT</sub> <sup>2</sup>	External Vss negative voltage control
21	A2	Address bit A2 connection
22	A1	Address bit A1 connection
23	LE	Serial interface latch enable input
24	CLK	Serial interface clock input
25	SI	Serial interface data input
26	C16 (D6) <sup>3</sup>	Parallel control bit, 16 dB
27	C8 (D5) <sup>3</sup>	Parallel control bit, 8 dB
28	C4 (D4) <sup>3</sup>	Parallel control bit, 4 dB
29	C2 (D3) <sup>3</sup>	Parallel control bit, 2 dB
30	C1 (D2) <sup>3</sup>	Parallel control bit, 1 dB
31	C0.5 (D1) <sup>3</sup>	Parallel control bit, 0.5 dB
32	C0.25 (D0) <sup>3</sup>	Parallel control bit, 0.25 dB
Pad	GND	Exposed pad: ground for proper operation

Notes: 1. RF pins 7 and 18 must be at 0V DC. The RF pins do not require DC blocking capacitors for proper operation if the 0V DC requirement is met

2. Use VSSEXT (pin 20) to bypass and disable internal

negative voltage generator. Connect Vssext (pin 20) to GND (Vssext = 0V) to enable internal negative voltage generator

3. Ground C0.25, C0.5, C1 C2, C4, C8, C16 if not in use

#### **Table 5. Operating Ranges**

Parameter	Symbol	Min	Тур	Max	Unit
Supply voltage (normal mode, Vss <sub>EXT</sub> = 0V) <sup>1</sup>	$V_{\text{DD}}$	2.3		5.5	v
Supply voltage (bypass mode, $Vss_{EXT} = -3.4V$ , $V_{DD} \ge 3.4V$ for full spec. compliance) <sup>2</sup>	$V_{DD}$	2.7	3.4	5.5	v
Negative supply voltage (bypass mode) <sup>2</sup>	Vss <sub>ext</sub>	-3.6		-2.4	v
Supply current (normal mode, Vss <sub>EXT</sub> = 0V) <sup>1</sup>	I <sub>DD</sub>		130	200	μA
Supply current (bypass mode, Vss <sub>EXT</sub> = -3.4V) <sup>2</sup>	I <sub>DD</sub>		50	80	μA
Negative supply current (bypass mode, Vss <sub>EXT</sub> = -3.4V) <sup>2</sup>	I <sub>SS</sub>	-40	-16		μA
Digital input high	V <sub>IH</sub>	1.17		3.6	V
Digital input low	V <sub>IL</sub>	-0.3		0.6	V
Digital input current				15	μA
RF input power, CW <sup>3</sup> 9 kHz < 50 MHz 50 MHz ≤ 8 GHz	P <sub>MAX,CW</sub>			see <i>Fig. 4</i> +28	dBm dBm
RF input power, pulsed⁴ 9 kHz < 50 MHz 50 MHz ≤ 8 GHz	P <sub>MAX,PULSED</sub>			see <i>Fig. 4</i> +31	dBm dBm
Operating temperature range	T <sub>OP</sub>	-40	25	+85	°C

Notes: 1. Normal mode: connect Vss<sub>EXT</sub> (pin 20) to GND (Vss<sub>EXT</sub> = 0V) to enable internal negative voltage generator 2. Bypass mode: use Vss<sub>EXT</sub> (pin 20) to bypass and disable internal

negative voltage generator

3. 100% duty cycle, all bands,  $50\Omega$ 

4. Pulsed, 5% duty cycle of 4620  $\mu s$  period,  $50\Omega$ 



#### **Table 6. Absolute Maximum Ratings**

Parameter/Condition	Symbol	Min	Max	Unit
Supply voltage	$V_{\text{DD}}$	-0.3	5.5	V
Digital input voltage	$V_{\text{CTRL}}$	-0.3	3.6	V
RF input power, max 9 kHz < 50 MHz 50 MHz ≤ 8 GHz	P <sub>MAX,ABS</sub>		see <i>Fig. 4</i> +34	dBm dBm
Storage temperature range	T <sub>ST</sub>	-65	+150	°C
ESD voltage HBM <sup>1</sup> , all pins	$V_{\text{ESD},\text{HBM}}$		1500	V
ESD voltage MM <sup>2</sup> , all pins	$V_{\text{ESD},\text{MM}}$		200	V
ESD voltage CDM <sup>3</sup> , all pins	V <sub>ESD,CDM</sub>		250	V

Notes: 1. Human Body Model (MIL-STD 883 Method 3015) 2. Machine Model (JEDEC JESD22-A115)

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

# **Electrostatic Discharge (ESD) Precautions**

When handling this UltraCMOS<sup>®</sup> device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

# Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS<sup>®</sup> devices are immune to latch-up.

# **Moisture Sensitivity Level**

The moisture sensitivity level rating for the PE43704 in the 5x5 QFN package is MSL1.

# **Switching Frequency**

The PE43704 has a maximum 25 kHz switching rate when the internal negative voltage generator is used (pin 20 = GND). The rate at which the PE43704 can be switched is only limited to the switching time (*Tables 1-3*) if an external negative supply is provided (pin 20 = Vss<sub>EXT</sub>).

Switching frequency is defined to be the speed at which the DSA can be toggled across attenuation states. Switching time is the time duration between the point the control signal reaches 50% of the final value and the point the output signal

# **Optional External Vss Control (Vss<sub>EXT</sub>)**

For proper operation, the Vss<sub>EXT</sub> control pin must be grounded or tied to the Vss voltage specified in *Table 5*. When the Vss<sub>EXT</sub> control pin is grounded, FETs in the switch are biased with an internal voltage generator. For applications that require the lowest possible spur performance, Vss<sub>EXT</sub> can be applied externally to bypass the internal

#### **Table 7. Latch and Clock Specifications**

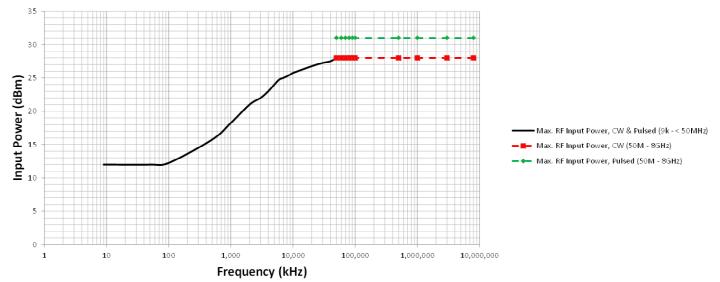
Latch Enable	Shift Clock	Function
0	<b>↑</b>	Shift register clocked
Ť	х	Contents of shift register transferred to attenuator core

# Safe Attenuation State Transitions

The PE43704 features a novel architecture to provide safe transition behavior when changing attenuation states. When RF input power is applied, positive output power spikes are prevented during attenuation state changes by optimized internal timing control.







# Figure 4. Power De-rating Curve (500, -40°C to 85°C Ambient)

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#### Table 8. Parallel Truth Table

	F	Parallel	Contro	ol Settir	ng		Attenuation
D6	D5	D4	D3	D2	D1	D0	Setting RF1-RF2
L	L	L	L	L	L	L	Reference I.L.
L	L	L	L	L	L	н	0.25 dB
L	L	L	L	L	н	L	0.5 dB
L	L	L	L	н	L	L	1 dB
L	L	L	н	L	L	L	2 dB
L	L	н	L	L	L	L	4 dB
L	н	L	L	L	L	L	8 dB
н	L	L	L	L	L	L	16 dB
н	Н	н	Н	н	Н	Н	31.75 dB

#### Table 10. Serial Address Word Truth Table

			Address					
A7 (MSB)	A6	A5	A4	A3	A2	A1	A0	Setting
х	Х	Х	Х	Х	L	L	L	000
х	Х	Х	Х	Х	L	L	н	001
х	Х	Х	Х	Х	L	н	L	010
х	Х	Х	Х	Х	L	н	н	011
х	Х	Х	Х	Х	Н	L	L	100
х	Х	Х	Х	Х	н	L	н	101
х	Х	Х	Х	Х	н	н	L	110
х	Х	Х	Х	Х	Н	Н	н	111

#### Table 11. Serial-Addressable Register Map

Bits can either be set to logic high or logic low															
MSB (last in) D7 must be set to logic low LSB (first in)															
Q15	Q14	Q13	Q12	Q11	Q10	Q9	Q8	Q7	Q6	Q5	Q4	Q3	Q2	Q1	QO
A7	A6	A5	A4	A3	A2	A1	A0	D7	D6	D5	D4	D3	D2	D1	D0

Address Word

Attenuation Word

Attenuation word is derived directly from the attenuation value. For example, to program the 18.25 dB state at address 3:

Address word: XXXXX011 Attenuation sord: Multiply by 4 and convert to binary  $\rightarrow$  4 \* 18.25 dB  $\rightarrow$  73  $\rightarrow$  01001001 Serial input: XXXXX01101001001

		At	tenuat	ion W	ord			Attenuation
D7	D6	D5	D4	D3	D2	D1	D0 (LSB)	Setting RF1-RF2
L	L	L	L	L	L	L	L	Reference I.L.
L	L	L	L	L	L	L	н	0.25 dB
L	L	L	L	L	L	н	L	0.5 dB
L	L	L	L	L	н	L	L	1 dB
L	L	L	L	н	L	L	L	2 dB
L	L	L	н	L	L	L	L	4 dB
L	L	н	L	L	L	L	L	8 dB
L	н	L	L	L	L	L	L	16 dB
L	Н	Н	Н	Н	Н	Н	н	31.75 dB

# Programming Options

# **Parallel/Serial Selection**

Either a parallel or serial-addressable interface can be used to control the PE43704. The  $\overline{P}/S$  bit provides this selection, with  $\overline{P}/S = LOW$  selecting the parallel interface and  $\overline{P}/S = HIGH$  selecting the serial-addressable interface.

# Parallel Mode Interface

The parallel interface consists of seven CMOScompatible control lines that select the desired attenuation state, as shown in *Table 8*.

The parallel interface timing requirements are defined by *Figure 6* (Parallel Interface Timing Diagram), *Table 13* (Parallel and Direct Interface AC Characteristics) and switching time (*Tables 1-3*).

For *latched*-parallel programming the latch enable (LE) should be held LOW while changing attenuation state control values, then pulse LE HIGH to LOW (*per Figure 6*) to latch new attenuation state into device.

For *direct* parallel programming, the LE line should be pulled HIGH. Changing attenuation state control values will change device state to new attenuation. Direct mode is ideal for manual control of the device (using hardwire, switches, or jumpers).

In parallel mode, serial-in (SI) and clock (CLK) pins are "don't care" and may be tied to logic LOW or logic HIGH.

# Serial Interface

The serial-addressable interface is a 16-bit serial-in, parallel-out shift register buffered by a transparent latch. The 16-bits make up two words comprised of 8bits each. The first word is the Attenuation Word, which controls the state of the DSA. The second word is the Address Word, which is compared to the static (or programmed) logical states of the A0, A1 and A2 digital inputs. If there is an address match, the DSA changes state; otherwise its current state will remain unchanged. *Figure 5* illustrates an example timing diagram for programming a state. It is required that all parallel control inputs be grounded when the DSA is used in serial-addressable mode.

The serial-interface is controlled using three CMOScompatible signals: serial-in (SI), clock (CLK), and latch enable (LE). The SI and CLK inputs allow data to be serially entered into the shift register. Serial data is clocked in LSB first, beginning with the attenuation word.

The shift register must be loaded while LE is held LOW to prevent the attenuator value from changing as data is entered. The LE input should then be toggled HIGH and brought LOW again, latching the new data into the DSA. Attenuation word and address word truth tables are listed in *Table 9 and Table 10*. A programming example of the serial register is illustrated in *Table 11*. The serial timing diagram is illustrated in *Figure 5*.

# **Power-up Control Settings**

The PE43704 will always initialize to the maximum attenuation setting (31.75 dB) on power-up for both the serial-addressable and latched-parallel modes of operation and will remain in this setting until the user latches in the next programming word. In direct -parallel mode, the DSA can be preset to any state within the 31.75 dB range by pre-setting the parallel control pins prior to power-up. In this mode, there is a 400-µs delay between the time the DSA is powered-up to the time the desired state is set. During this power-up delay, the device attenuates to the maximum attenuation setting (31.75 dB) before defaulting to the user defined state. If the control pins are left floating in this mode during power-up, the device will default to the minimum attenuation setting (insertion loss state).

Dynamic operation between serial and parallel programming modes is possible.

If the DSA powers up in serial mode ( $\overline{P}/S = HIGH$ ), all the parallel control inputs DI[6:0] must be set to logic low. Prior to toggling to parallel mode, the DSA *must* be programmed serially to ensure D[7] is set to logic low.

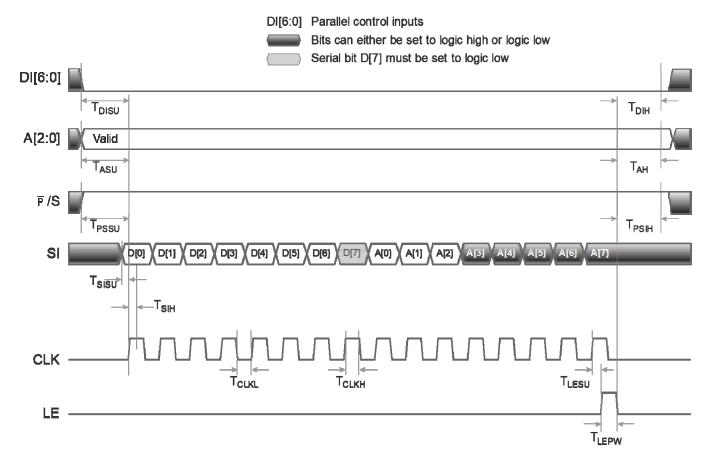
If the DSA powers up in either latched or directparallel mode, all parallel pins DI[6:0] must be set to logic low prior to toggling to serial-addressable mode ( $\overline{P}/S = HIGH$ ), and *held* low until the DSA has been programmed serially to ensure bit D[7] is set to logic low.

The sequencing is only required once on power-up. Once completed, the DSA may be toggled between serial and parallel programming modes at will.

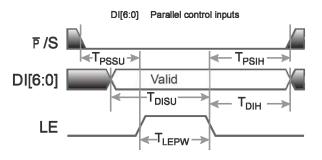




# Figure 5. Serial Addressable Timing Diagram



# Figure 6. Latched-Parallel/Direct-Parallel Timing Diagram





# Table 12. Serial Interface AC Characteristics

 $V_{\text{DD}}$  = 3.4V or 5.0V, -40°C <  $T_{\text{A}}$  < 85°C, unless otherwise specified

Parameter	Symbol	Min	Max	Unit
Serial clock frequency	F <sub>CLK</sub>	-	10	MHz
Serial clock HIGH time	T <sub>CLKH</sub>	30	-	ns
Serial clock LOW time	T <sub>CLKL</sub>	30	-	ns
Last serial clock rising edge setup time to Latch Enable rising edge	T <sub>LESU</sub>	10	-	ns
Latch enable min. pulse width	T <sub>LEPW</sub>	30	-	ns
Serial data setup time	T <sub>SISU</sub>	10	-	ns
Serial data hold time	T <sub>SIH</sub>	10	-	ns
Parallel data setup time		100	-	ns
Parallel data hold time	T <sub>DIH</sub>	100	-	ns
Address setup time	T <sub>ASU</sub>	100	-	ns
Address hold time	Т <sub>АН</sub>	100	-	ns
Parallel/serial setup time	T <sub>PSSU</sub>	100	-	ns
Parallel/serial hold time	T <sub>PSIH</sub>	100	-	ns

# Table 13. Parallel and Direct Interface AC Characteristics

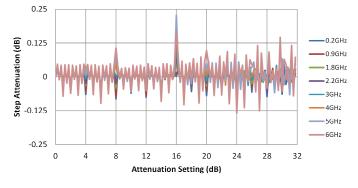
 $V_{\text{DD}}$  = 3.4V or 5.0V, -40°C <  $T_{\text{A}}$  < 85°C, unless otherwise specified

Symbol	Parameter	Min	Max	Unit
T <sub>LEPW</sub>	Latch enable minimum pulse width	30	-	ns
T <sub>DISU</sub>	Parallel data setup time	100	-	ns
T <sub>DIH</sub>	Parallel data hold time	100	-	ns
T <sub>PSSU</sub>	Parallel/serial setup time	100	-	ns
T <sub>PSIH</sub>	Parallel/serial hold time	100	-	ns



# Typical Performance Data, 0.25 dB Step @ 25°C and V<sub>DD</sub> = 3.4V unless otherwise specified

# Figure 7. 0.25 dB Step Attenuation vs. Frequency\*



\* Monotonicity is held so long as step-attenuation does not cross below -0.25 dB

Figure 8. 0.25 dB Step, Actual vs. Frequency

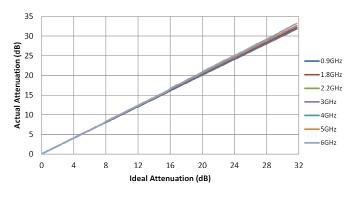
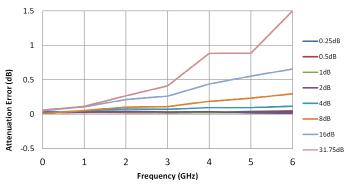


Figure 9. 0.25 dB Major State Bit Error vs. Attenuation Setting



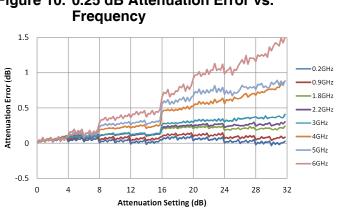
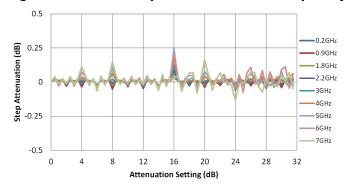


Figure 10. 0.25 dB Attenuation Error vs.



# Typical Performance Data, 0.5 dB Step @ $25^{\circ}$ C and V<sub>DD</sub> = 3.4V unless otherwise specified Figure 11. 0.5 dB Step Attenuation vs. Frequency\*



\* Monotonicity is held so long as step-attenuation does not cross below -0.5 dB

Figure 12. 0.5 dB Step, Actual vs. Frequency

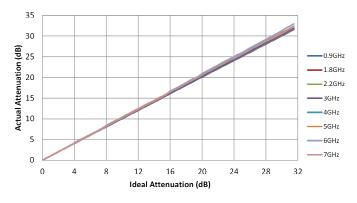


Figure 13. 0.5 dB Major State Bit Error vs. Attenuation Setting

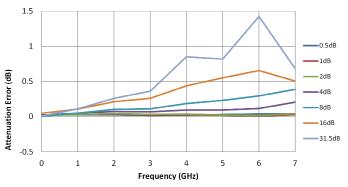
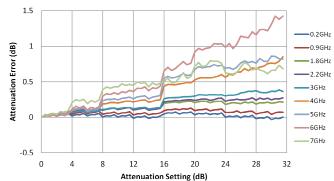
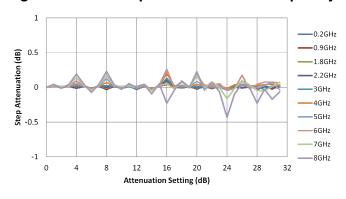


Figure 14. 0.5 dB Attenuation Error vs. Frequency



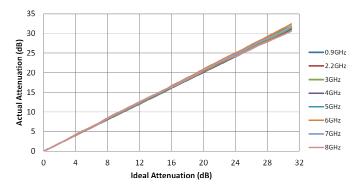


# Typical Performance Data, 1 dB Step @ $25^{\circ}$ C and V<sub>DD</sub> = 3.4V unless otherwise specified Figure 15. 1 dB Step Attenuation vs. Frequency\*

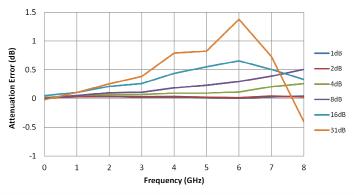


 $^{\ast}$  Monotonicity is held so long as step-attenuation does not cross below –1.0 dB

Figure 16. 1 dB Step, Actual vs. Frequency









# Typical Performance Data, 1 dB Step @ $25^{\circ}$ C and V<sub>DD</sub> = 3.4V unless otherwise specified Figure 18. 1 dB Attenuation Error vs. Frequency

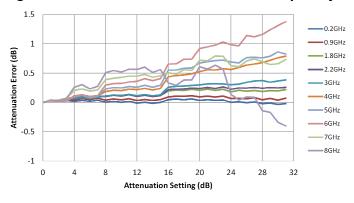


Figure 19. Insertion Loss vs. Temperature

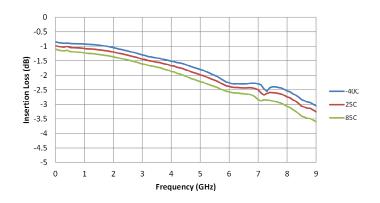
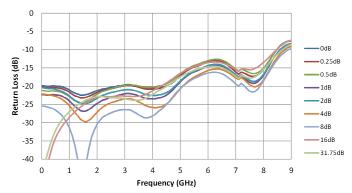
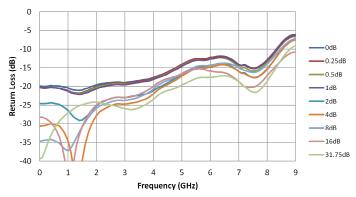


Figure 20. Input Return Loss vs. Attenuation Setting







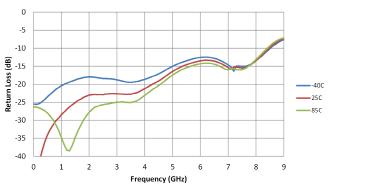
-5

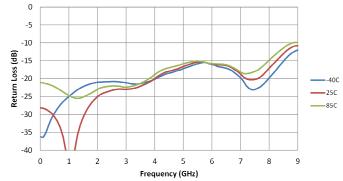


# Typical Performance Data, 1 dB Step @ $25^{\circ}$ C and V<sub>DD</sub> = 3.4V unless otherwise specified





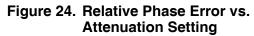








# Typical Performance Data @ 25°C and V<sub>DD</sub> = 3.4V unless otherwise specified



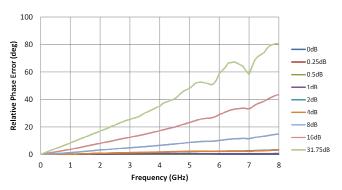


Figure 26. Attenuation Error @ 900 MHz vs. Temperature

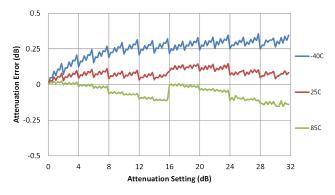
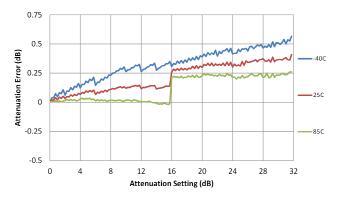
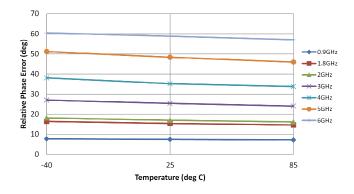


Figure 28. Attenuation Error @ 3000 MHz vs. Temperature







#### Figure 27. Attenuation Error @ 1800 MHz vs. Temperature

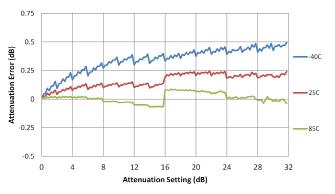
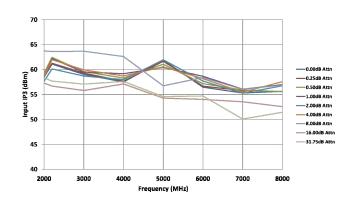


Figure 29. IIP3 vs. Attenuation Setting





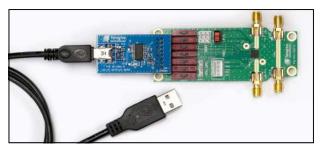
# **Evaluation Kit**

The Digital Attenuator Evaluation Board (EVB) was designed to ease customer evaluation of the PE43704 digital step attenuator. PE43704 EVB supports direct-parallel, latched-parallel, and serial modes.

#### Evaluation Kit Setup

Connect the EVB with the USB dongle board and USB cable as shown in *Figure 30*.

# Figure 30. Evaluation Kit



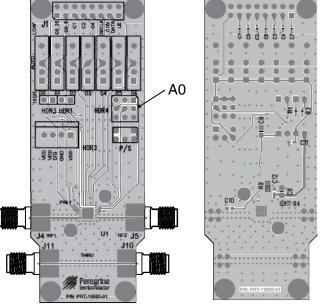
# Direct-Parallel Programming Procedure

Direct-parallel programming is suitable for manual operation without software programming. For manual direct-parallel programming, position the parallel/serial (P/S) select switch to the parallel (or left) position. The LE pin of J1 (pin 15) must be tied to HIGH voltage. Switches D0–D6 are SP3T switches that enable the user to manually program the parallel bits. When D0–D6 are toggled to the 'HIGH' position, logic high is presented to the parallel input. When toggled to the 'LOW' position, logic low is presented to the parallel input. Setting D0–D6 to the 'AUTO' position presents as OPEN, which is set for software programming of latchedparallel and serial mode. *Table 8* depicts the parallel programming truth table.

# Latched-Parallel Programming Procedure

For automated latched-parallel programming, connect the USB dongle board and cable that is provided with the evaluation kit (EVK) from the USB port of the PC to the J1 header of the PE43704 EVB, and set the D0–D6 SP3T switches to the 'AUTO' position. Position the parallel/serial (P/S) select switch to the parallel (or left) position.

## Figure 31. Evaluation Board Layout



PRT-13505

The evaluation software is written to operate the DSA in parallel mode. Ensure that the software GUI is set to latched-parallel mode. Use the software GUI to enable the desired attenuation state. The software GUI automatically programs the DSA each time an attenuation state is enabled.

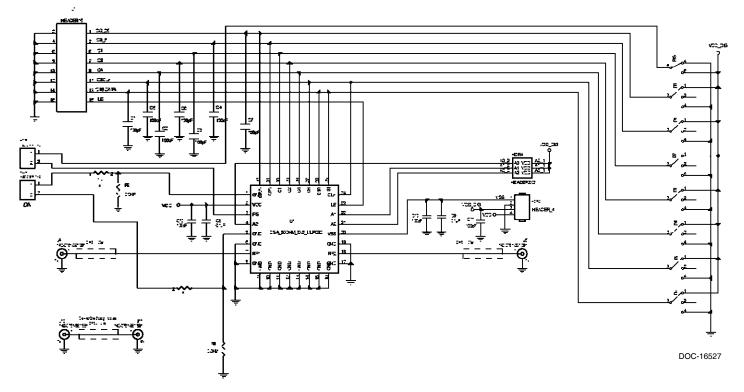
# Serial-Addressable Programming Procedure

For automated serial programming, connect the USB dongle board and cable that is provided with the evaluation kit (EVK) from the USB port of the PC to the J1 header of the PE43704 EVB, and set the D0–D6 SP3T switches to the 'AUTO' toggle position. Position the parallel/serial (P/S) select switch to the serial (or right) position. Prior to programming, the user must define an address setting using the HDR4 header pin. Jump the middle row of pins on the HDR4 header (A0-A2) to the lower row of pins to set logic low, or jump the middle row of pins to the upper row of pins to set logic high. If the HDR4 pins are left open, then 000 becomes the default address. The software GUI is written to operate the DSA in serial mode. Use the software GUI to enable each setting to the desired attenuation state. The software GUI automatically programs the DSA each time an attenuation state is enabled.

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# Figure 32. Evaluation Board Schematic



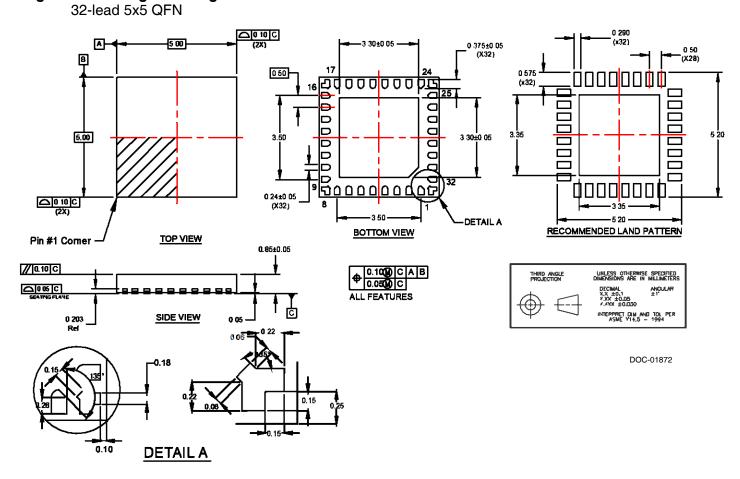
VOTES.

- USE (FRT-13000-0) PUB 2 CAL TOX

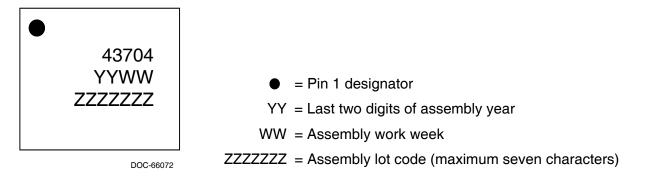
2 CALTON JON TANSPARTS AND ASSEMBLES SUBCEPTIBLE TO DAMAGE & FELECTROSTATIC DISCHARGE (ES JI



# Figure 33. Package Drawing

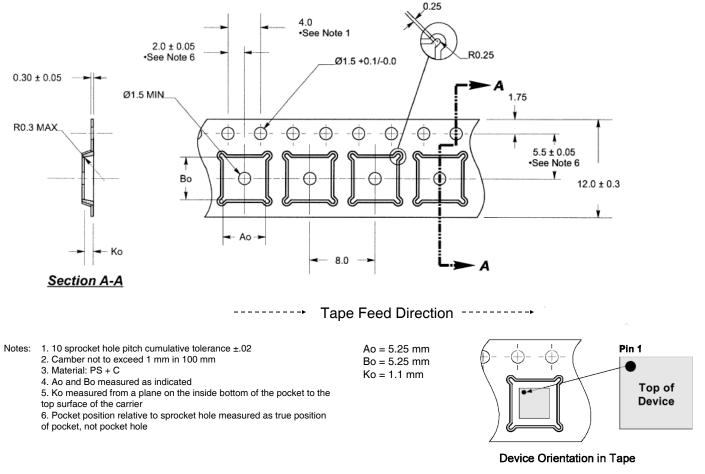


# Figure 34. Top Marking Specification





#### Figure 35. Tape and Reel Drawing



# Table 14. Ordering Information

Order Code	Description	Package	Shipping Method
PE43704B-Z	PE43704 Digital step attenuator	32-lead 5x5 mm QFN	3000 units / T&R
EK43704-12	PE43704 Evaluation kit	Evaluation kit	1 / Box

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For sales and contact information please visit www.psemi.com.

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